



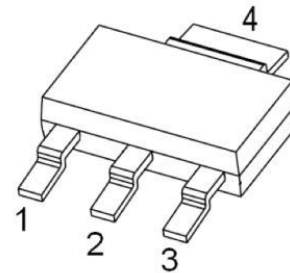
SSCN4350GS5

NPN Plastic-Encapsulate Transistors

➤ Description

This product has the characteristics of high current and high-power consumption. It is universal and suitable for many different applications. It can be used for power amplifiers and switches that require collector currents up to 3A.

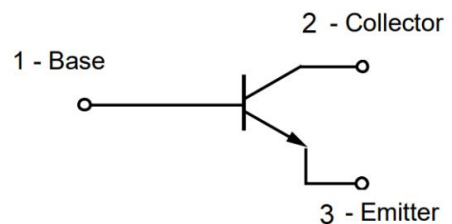
➤ Pin configuration



SOT-223

➤ Features

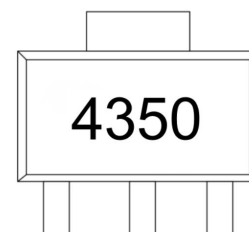
- General-purpose high-voltage amplifiers
- Gas discharge display drivers
- Medium power amplification and switching



Circuit Diagram

➤ Ordering Information

Device	Package	Shipping
SSCN4350GS5	SOT-223	2500/Reel



Marking (Top View)



➤ **Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)**

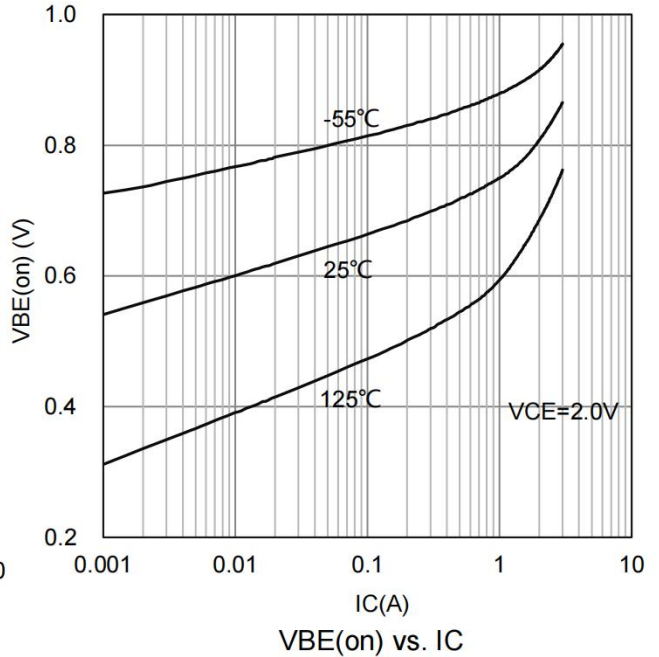
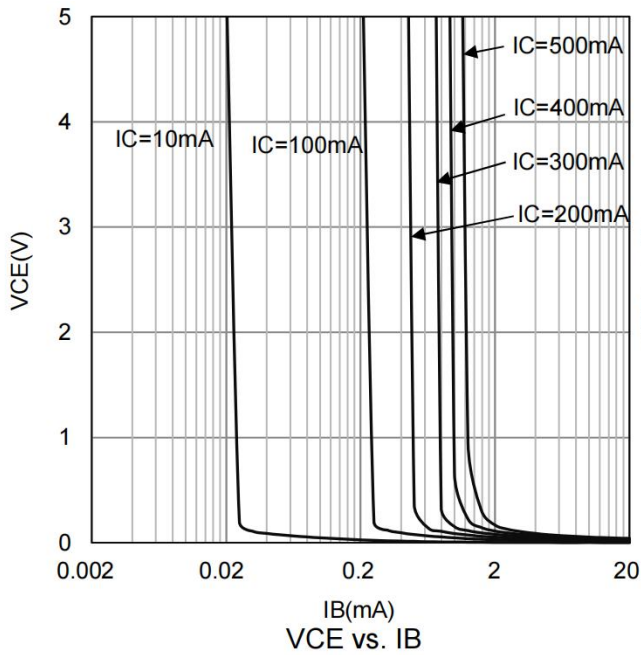
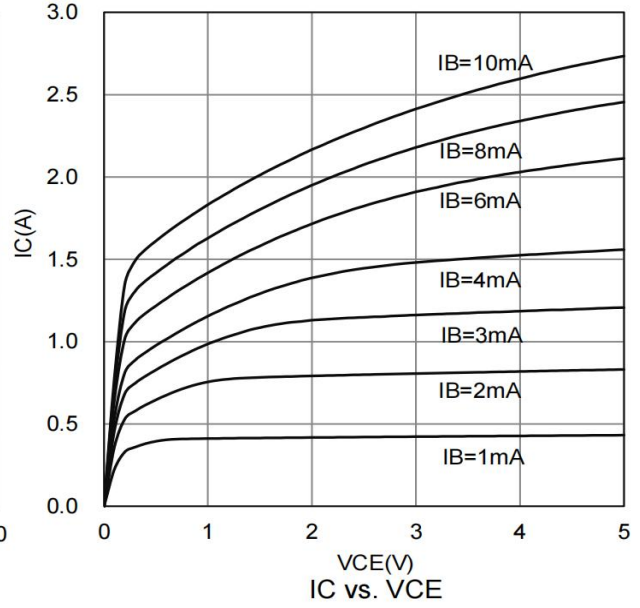
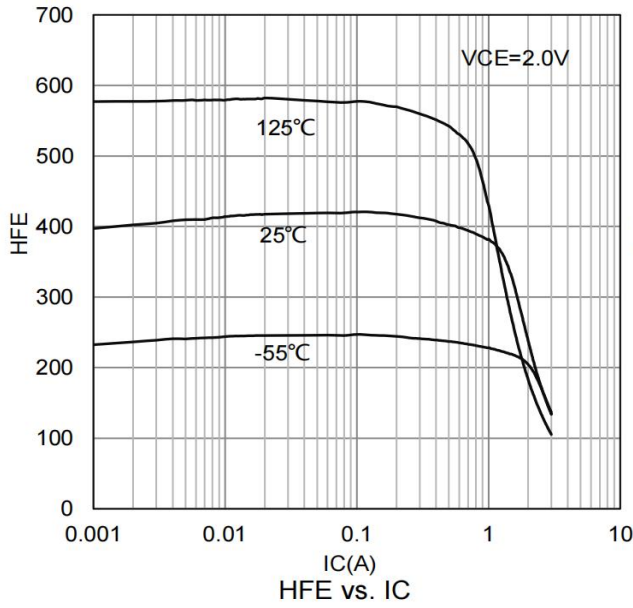
Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CB0}	60	V
Collector- Emitter Voltage	V_{CE0}	50	V
Emitter-Base Voltage	V_{EB0}	6	V
Collector Current-Continuous	I_C	3	A
Collector Power Dissipation	P_C	0.83	W
Thermal Resistance From Junction To Ambient	$R_{\theta JA}$	150	$^\circ\text{C}/\text{W}$
Junction Temperature	T_J	-55 to 150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55 to 150	$^\circ\text{C}$

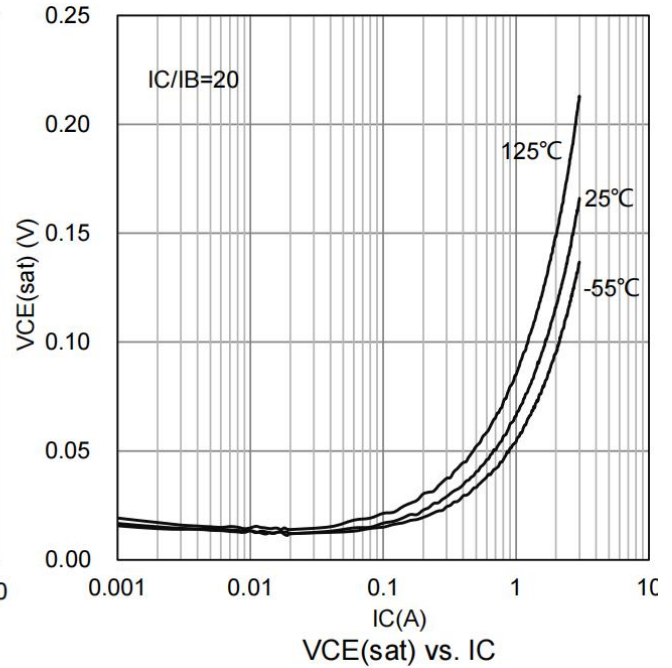
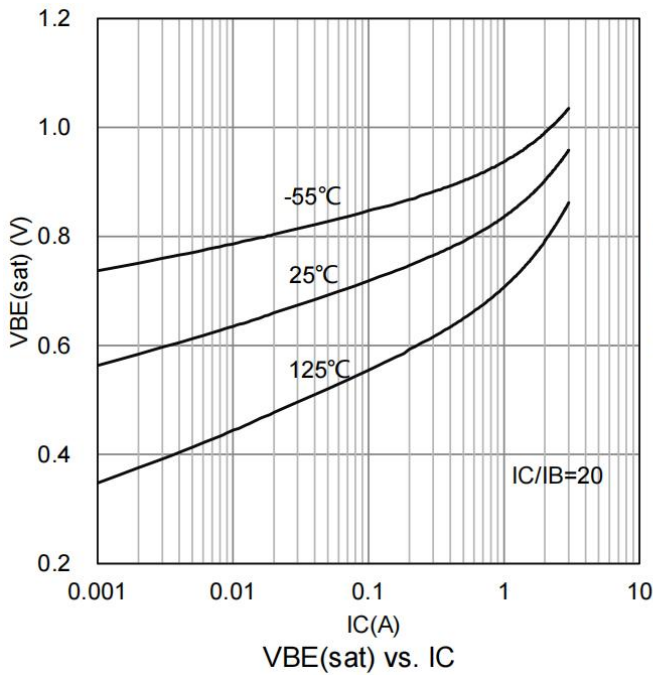
➤ **Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)**

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	BV_{CB0}	$I_C=100\mu\text{A}, I_E=0$	60			V
Collector-emitter Breakdown Voltage	BV_{CE0}	$I_C=10\text{mA}, I_B=0$	50			V
Emitter -Base Breakdown Voltage	BV_{EB0}	$I_E=100\mu\text{A}, I_C=0$	6			V
Collector Cutoff Current	I_{CB0}	$V_{CB}=40\text{V}, I_E=0$			1	μA
Emitter Cut-off Current	I_{EB0}	$V_{EB}=4\text{V}, I_C=0$			1	μA
Collector-Emitter cutoff Current	I_{CE0}	$V_{CE}=40\text{V}, I_B=0$			10	μA
DC Current Gain	h_{FE1}	$V_{CE}=2\text{V}, I_C=100\text{mA}$	200		500	
DC Current Gain	H_{FE2}	$V_{CE}=2\text{V}, I_C=3\text{A}$	35			
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=2\text{A}, I_B=100\text{mA}$			0.5	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=2\text{A}, I_B=100\text{mA}$			1.2	V
Transition frequency	f_T	$V_{CE}=10\text{V}, I_C=50\text{mA}$ $f=100\text{MHz}$		150		MHz

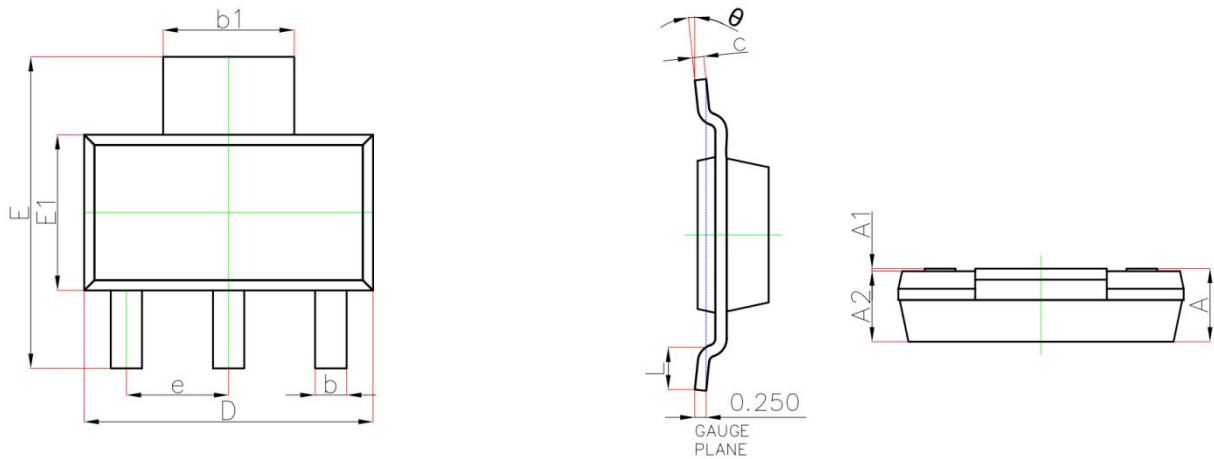


➤ Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)





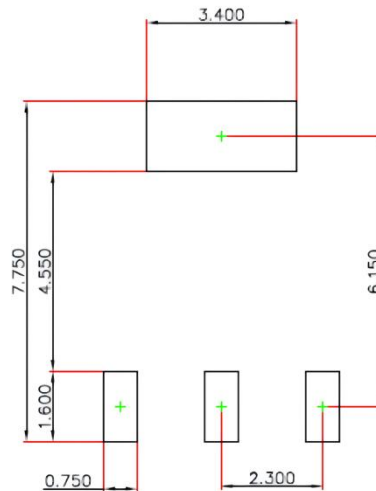
➤ Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	—	1.800	—	0.071
A1	0.020	0.100	0.001	0.004
A2	1.500	1.700	0.059	0.067
b	0.660	0.840	0.026	0.033
b1	2.900	3.100	0.114	0.122
c	0.230	0.350	0.009	0.014
D	6.300	6.700	0.248	0.264
E	6.700	7.300	0.264	0.287
E1	3.300	3.700	0.130	0.146
e	2.300(BSC)		0.091(BSC)	
L	0.750	—	0.030	—
θ	0°	10°	0°	10°



- Recommended Pad outline (Unit: mm)



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